

CMOS Hex Schmitt Triggers

High-Voltage Types (20-Volt Rating)

■ CD40106B consists of six Schmitt-trigger circuits. Each circuit functions as an inverter with Schmitt-trigger action on the input. The trigger switches at different points for positive- and negative-going signals. The difference between the positive-going voltage (V_P) and the negative-going voltage (V_N) is defined as hysteresis voltage (V_H) (see Fig.6). The CD40106B types are supplied in 14-lead hermetic dual-in-line ceramic packages (D and F suffixes), 14-lead dual-in-line plastic package (E suffix), and in chip form (H suffix).

Features:

- Schmitt-trigger action with no external components
- Hysteresis voltage (typ.) 0.9 V at $V_{DD} = 5$ V, 2.3 V at $V_{DD} = 10$ V, and 3.5 V at $V_{DD} = 15$ V
- Noise immunity greater than 50%
- No limit on input rise and fall times
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μ A at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Low V_{DD} to V_{SS} current during slow input ramp
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- Wave and pulse shapers
- High-noise-environment systems
- Monostable multivibrators
- Astable multivibrators

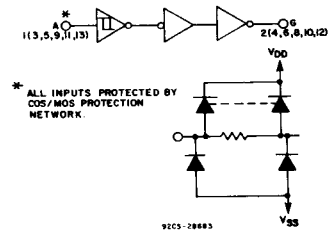
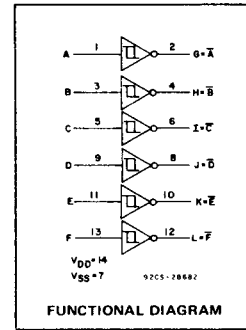


Fig.1 - Logic diagram (1 of 6 Schmitt triggers).

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})		
Voltages referenced to V_{SS} Terminal		
INPUT VOLTAGE RANGE, ALL INPUTS		-0.5V to +20V
DC INPUT CURRENT, ANY ONE INPUT		± 10 mA
POWER DISSIPATION PER PACKAGE (P_D):		
For $T_A = -55^\circ\text{C}$ to $+100^\circ\text{C}$		500mW
For $T_A = +100^\circ\text{C}$ to $+125^\circ\text{C}$		Derate Linearly at 12mW/ $^\circ\text{C}$ to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR		
FOR $T_A = \text{FULL PACKAGE-TEMPERATURE RANGE (All Package Types)}$		100mW
OPERATING-TEMPERATURE RANGE (T_A)		-55°C to $+125^\circ\text{C}$
STORAGE TEMPERATURE RANGE (T_{stg})		-65°C to $+150^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):		
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79mm) from case for 10s max		$+265^\circ\text{C}$

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply-Voltage Range (For T_A Full Package Temperature Range)	3	18	V

DYNAMIC ELECTRICAL CHARACTERISTICS

At $T_A = 25^\circ\text{C}$, Input $t_r, t_f = 20$ ns, $C_L = 50$ pF, $R_L = 200$ k Ω

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS	
		V_{DD} (V)	TYP.		MAX.
Propagation Delay Time:	t_{PHL} , t_{PLH}	5	140	280	ns
		10	70	140	
		15	60	120	
Transition Time:	t_{THL} , t_{TLH}	5	100	200	ns
		10	50	100	
		15	40	80	
Input Capacitance, C_{IN}	Any Input		5	7.5	pF

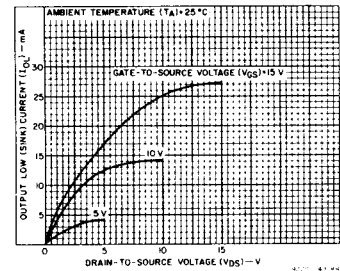


Fig.2 - Typical output low (sink) current characteristics.

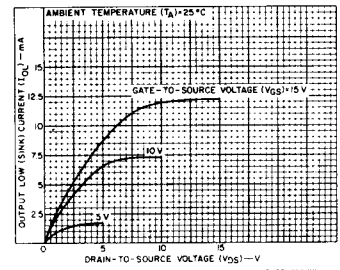


Fig.3 - Minimum output low (sink) current characteristics.

CD40106B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS	
	V _O (V)	V _{IN} (V)	V _{DD} (V)	-55	-40	+85	+125	+25				
								Min.	Typ.	Max.		
Quiescent Device Current, I _{DD} Max.	-	0,5	5	1	1	30	30	-	0,02	1	μA	
	-	0,10	10	2	2	60	60	-	0,02	2		
	-	0,15	15	4	4	120	120	-	0,02	4		
	-	0,20	20	20	20	600	600	-	0,04	20		
Positive Trigger Threshold Voltage V _p Min.	-	-	5	2,2	2,2	2,2	2,2	2,2	2,9	-	V	
	-	-	10	4,6	4,6	4,6	4,6	4,6	5,9	-		
	-	-	15	6,8	6,8	6,8	6,8	6,8	8,8	-		
	-	-	5	3,6	3,6	3,6	3,6	-	2,9	3,6		
V _p Max.	-	-	10	7,1	7,1	7,1	7,1	-	5,9	7,1	V	
	-	-	15	10,8	10,8	10,8	10,8	-	8,8	10,8		
	-	-	5	0,9	0,9	0,9	0,9	0,9	1,9	-		V
	-	-	10	2,5	2,5	2,5	2,5	2,5	3,9	-		
-	-	15	4	4	4	4	4	5,8	-			
-	-	5	2,8	2,8	2,8	2,8	-	1,9	2,8			
V _N Max.	-	-	10	5,2	5,2	5,2	5,2	-	3,9	5,2	V	
	-	-	15	7,4	7,4	7,4	7,4	-	5,8	7,4		
	-	-	5	0,3	0,3	0,3	0,3	0,3	0,9	-		V
	-	-	10	1,2	1,2	1,2	1,2	1,2	2,3	-		
-	-	15	1,6	1,6	1,6	1,6	1,6	3,5	-			
-	-	5	1,6	1,6	1,6	1,6	-	0,9	1,6			
V _H Max.	-	-	10	3,4	3,4	3,4	3,4	-	2,3	3,4	V	
	-	-	15	5	5	5	5	-	3,5	5		
	0,4	0,5	5	0,64	0,61	0,42	0,36	0,51	1	-		mA
	0,5	0,10	10	1,6	1,5	1,1	0,9	1,3	2,6	-		
1,5	0,15	15	4,2	4	2,8	2,4	3,4	6,8	-			
4,6	0,5	5	-0,64	-0,61	-0,42	-0,36	-0,51	-1	-			
Output High (Source) Current, I _{OH} Min.	2,5	0,5	5	-2	-1,8	-1,3	-1,15	-1,6	-3,2	-		
	9,5	0,10	10	-1,6	-1,5	-1,1	-0,9	-1,3	-2,6	-		
	13,5	0,15	15	-4,2	-4	-2,8	-2,4	-3,4	-6,8	-		
	-	5	5	0,05			-	0	0,05	V		
-	10	10	0,05			-	0	0,05				
-	15	15	0,05			-	0	0,05				
Output Voltage High Level, V _{OH} Min.	-	0	5	4,95			4,95	5	-	V		
	-	0	10	9,95			9,95	10	-			
	-	0	15	14,95			14,95	15	-			
	-	-	-	-	-	-	-	-	-			
Input Current, I _{IN} Max.	-	0,18	18	±0,1	±0,1	±1	±1	-	±10 ⁻⁵	±0,1	μA	

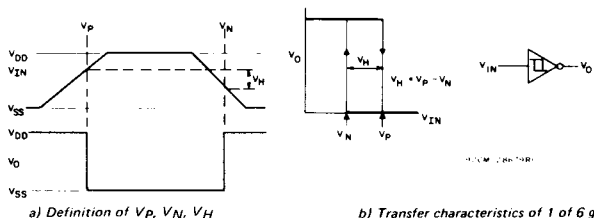


Fig. 6 - Hysteresis definition, characteristics, and test set-up.

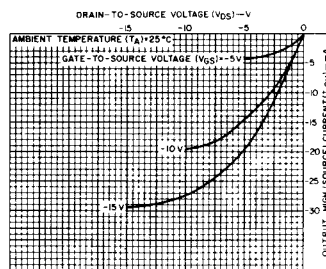


Fig. 4 - Typical output high (source) current characteristics.

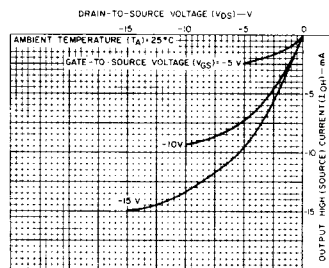


Fig. 5 - Minimum output high (source) current characteristics.

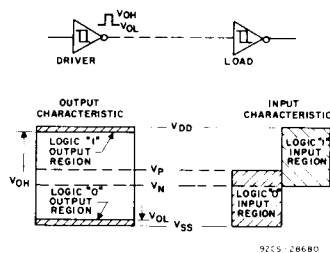


Fig. 7 - Input and output characteristics.

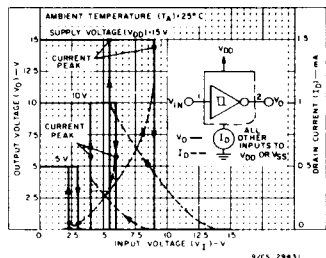


Fig. 8 - Typical current and voltage transfer characteristics.

3
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CD40106B Types

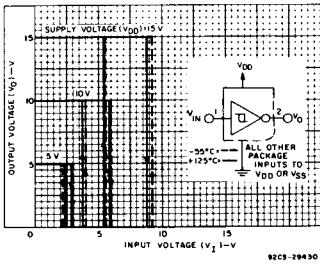


Fig. 9 - Typical voltage transfer characteristics as a function of temperature.

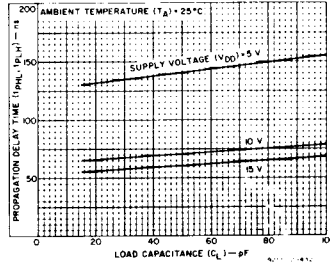


Fig. 10 - Typical propagation delay time as a function of load capacitance.

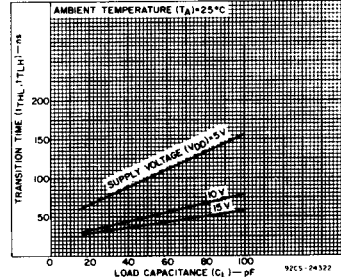


Fig. 11 - Typical transition time as a function of load capacitance.

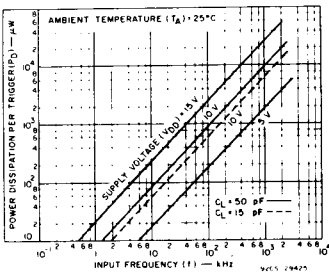


Fig. 12 - Typical power dissipation per trigger as a function of input frequency.

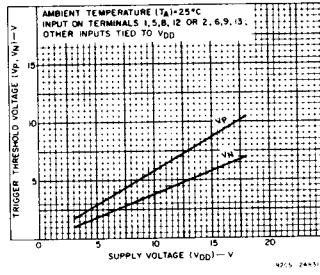


Fig. 13 - Typical trigger threshold voltage as a function of supply voltage.

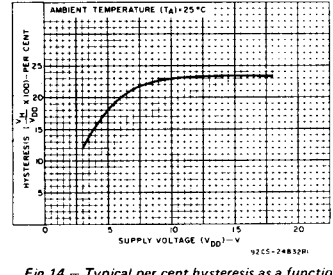


Fig. 14 - Typical per cent hysteresis as a function of supply voltage.

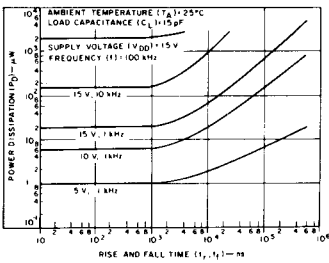


Fig. 15 - Typical power dissipation as a function of rise and fall times.

APPLICATIONS

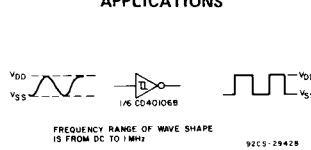


Fig. 16 - Wave shaper.

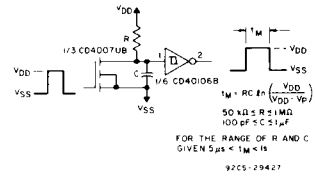


Fig. 17 - Monostable multivibrator.

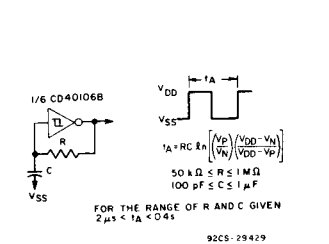


Fig. 18 - Astable multivibrator.

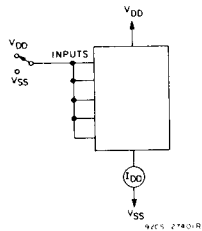


Fig. 19 - Quiescent device current test circuit.

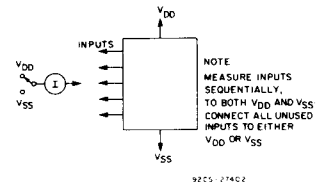


Fig. 20 - Input current test circuit.

CD40106B Types

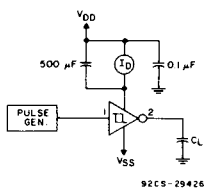
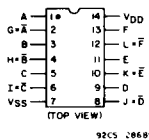
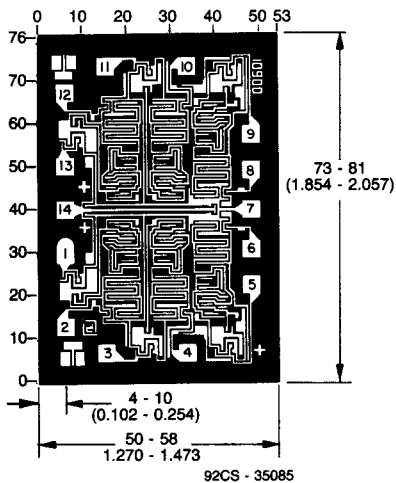


Fig.21 – Dynamic power dissipation test circuit.



TERMINAL ASSIGNMENT



Dimensions and Pad Layout for CD40106BH

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).